



VDC	1200 V
Q <sub>C</sub>	52/104 nC*
I <sub>F</sub> (V <sub>F</sub> =1.5V)	15/30 A*
	*Per Leg/Device

**Amp+™ Features**

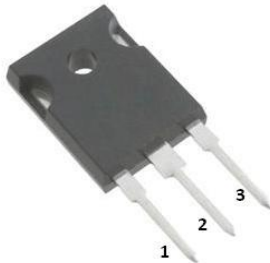
- High surge current capable
- Zero reverse recovery current
- High bandwidth
- Fast, temperature-independent switching

**Amp+™ Benefits**

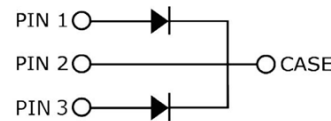
- Unipolar rectifier
- Zero switching loss
- Higher efficiency
- Smaller heat sink
- Parallel devices with thermal stability

**Amp+™ Applications**

- Motor drives
- Switch mode power supplies
- Power factor correction
- Diode snubber



Part #	Package	Marking
GDP30D120B	TO-247-3	GDP30D120



Maximum Rating Per Leg	Symbol	Conditions	Value	Unit
Continuous forward current	I <sub>F</sub>	T <sub>C</sub> =25 °C, T <sub>J</sub> =175 °C	28	A
		T <sub>C</sub> =125 °C, T <sub>J</sub> =175 °C	15	
		T <sub>C</sub> =150 °C, T <sub>J</sub> =175 °C	10	
Surge non-repetitive forward current sine halfwave	I <sub>F,SM</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	120	A
		T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	75	
Non-repetitive peak forward current	I <sub>F,max</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =10 μs	300	A
i <sup>2</sup> t value	∫i <sup>2</sup> dt	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	60	A <sup>2</sup> s
		T <sub>C</sub> =150 °C, t <sub>p</sub> =8.3 ms	23	
Repetitive peak reverse voltage	V <sub>RRM</sub>	T <sub>J</sub> =25 °C	1200	V
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	50	V/ns
Power dissipation	P <sub>tot</sub>	T <sub>C</sub> =25 °C	115	W
Operating & storage temperature	T <sub>C</sub> , T <sub>storage</sub>	Continuous	-55...135	°C
Soldering temperature	T <sub>solder</sub>	Wave soldering leads	260	°C
Mounting torque		M3 Screw	1	N-m

**Electrical Characteristics**, at T<sub>J</sub>=25 °C, unless otherwise specified

Static Characteristics Per Leg	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
DC blocking voltage	V <sub>DC</sub>		1200	-	-	V
Diode forward voltage	V <sub>F</sub>	I <sub>F</sub> =15A, T <sub>J</sub> =25 °C	-	1.5	1.7	
		I <sub>F</sub> =15A, T <sub>J</sub> =175 °C	-	2.5	2.8	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1,200V, T <sub>J</sub> =25 °C	-	4.1	100	μA
		V <sub>R</sub> =1,200V, T <sub>J</sub> =175 °C	-	1679	-	

# 1200V SiC Schottky Diode

Amp+™

GDP30D120B

Parameter	Symbol	Conditions	Values			Unit
			min.	typ.	max.	

### AC Characteristics Per Leg

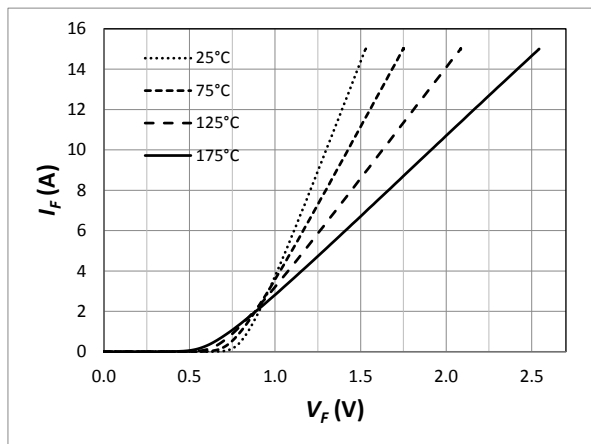
Total capacitive charge	$Q_{rr}$	$V_R=1,200V, T_j=27\text{ }^\circ\text{C}$	-	52	-	nC
Switching time	$t_c$	$di_F/dt=200\text{ A}/\mu\text{s}$ $T_j=150\text{ }^\circ\text{C}$	-	-	<10	ns
Total capacitance	C	$V_R=1\text{ V}, f=1\text{ MHz}$	-	895	-	pF
		$V_R=600V, f=1\text{ MHz}$	-	52	-	
		$V_R=1,200V, f=1\text{ MHz}$	-	43	-	

### Thermal Characteristics Per Leg

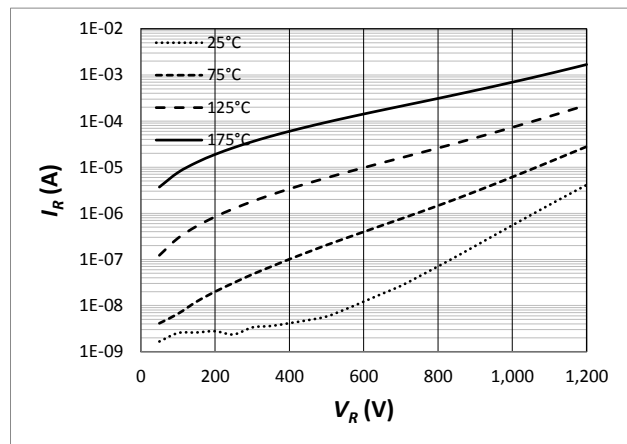
Thermal resistance, junction-case	$R_{thJC}$	Package (flange) mount	-	1.30	-	$^\circ\text{C}/\text{W}$
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### Typical Performance Per Leg

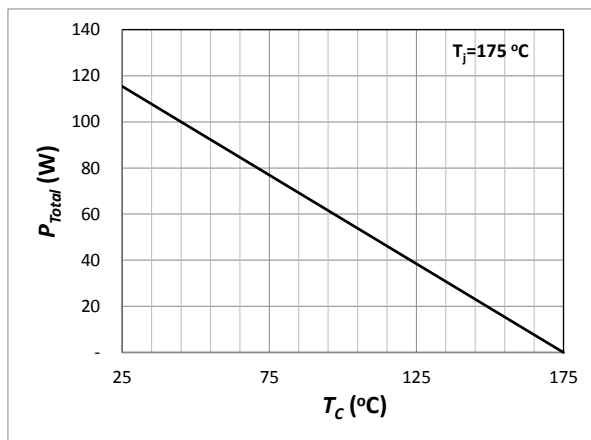
Forward Characteristics (parameterized on  $T_j$ )



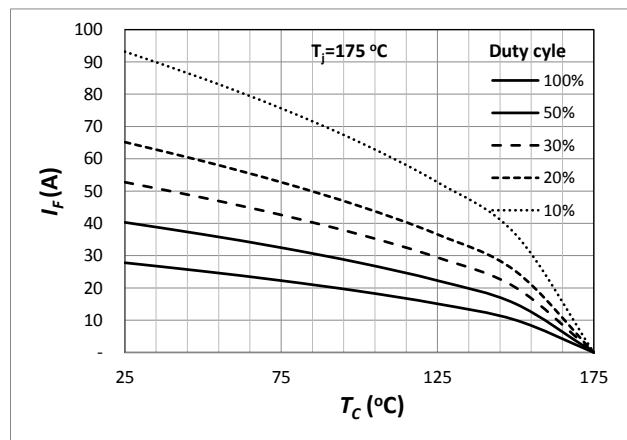
Reverse Characteristics (parameterized on  $T_j$ )



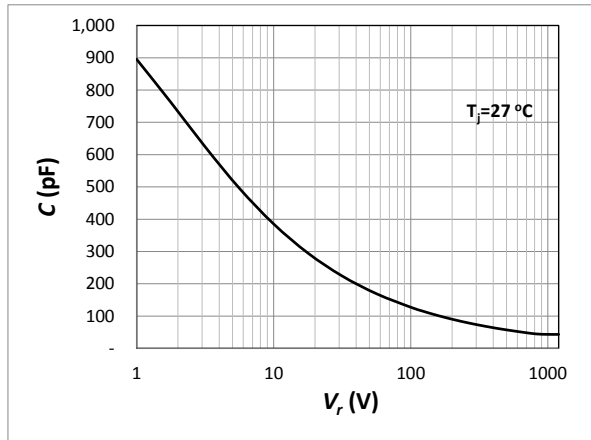
Power Derating



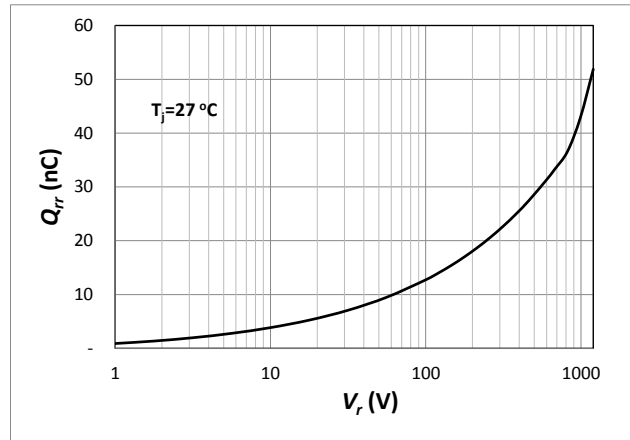
Current Derating



### Capacitance

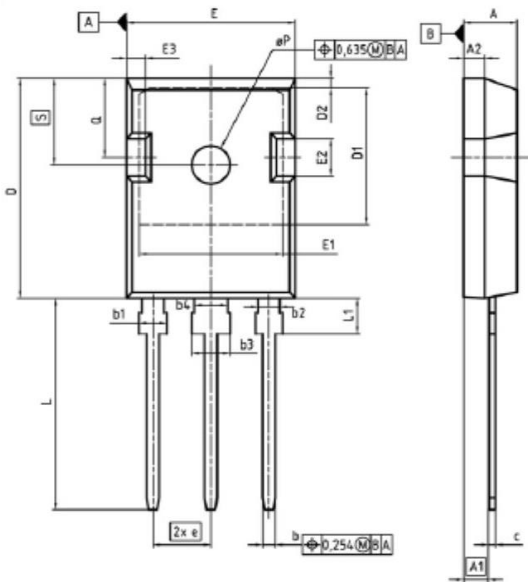


### Recovery Charge



### Package Dimensions

#### Package TO-247-3



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.23	5.21	0.166	0.205
A1	2.27	2.54	0.089	0.100
A2	1.65	2.16	0.073	0.085
b	1.07	1.33	0.042	0.052
b1	1.90	2.41	0.075	0.095
b2	1.90	2.16	0.075	0.085
b3	2.27	3.35	0.113	0.133
b4	2.27	3.13	0.113	0.123
c	0.35	0.68	0.022	0.027
D	20.99	21.10	0.819	0.831
D1	16.25	17.65	0.640	0.695
D2	0.95	1.35	0.037	0.053
E	15.70	16.13	0.618	0.635
E1	13.10	14.15	0.516	0.557
E2	3.03	5.10	0.145	0.201
E3	1.60	2.60	0.039	0.102
e	0.44 (BSC)		0.214 (BSC)	
H	3		3	
L	19.80	25.32	0.780	0.990
L1	4.10	4.47	0.161	0.176
eP	3.90	3.75	0.138	0.148
Q	5.49	6.00	0.216	0.236
S	8.04	8.30	0.238	0.248

#### Note

##### RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of [www.gptechgroup.com](http://www.gptechgroup.com).

##### REACH Compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at GPTG Headquarters in Lake Forest, California to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control.

Global Power Technologies Group Inc., Reserves the right to make changes to the product specifications and data in this document without notice.